Full Feature Peak Reducing EMI Solution

Features

- **Cypress PREMIS™ family offering**
- **Generates an EMI optimized clocking signal at the output**
- **Selectable output frequency range**
- **Single 1.25%, 3.75% down or center spread output**
- **Integrated loop filter components**
- **Operates with a 3.3 or 5V supply**
- **Low power CMOS design**
- **Available in 14-pin SOIC (Small Outline Integrated Circuit)**
- **Industrial Temperature Range Supported**

Key Specifications

Supply Voltages: ....V_{DD} = 3.3V±5%
or V_{DD} = 5V±10%

Frequency Range: .... 28 MHz ≤ F_{in} ≤ 75 MHz

Crystal Reference Range:................ 28 MHz ≤ F_{in} ≤ 40 MHz

Cycle to Cycle Jitter: .... 300 ps (max.)

Selectable Spread Percentage: ....1.25% or 3.75%

Output Duty Cycle: .... 40/60% (worst case)

Output Rise and Fall Time: .... 5 ns (max.)

Table 1. Modulation Width Selection

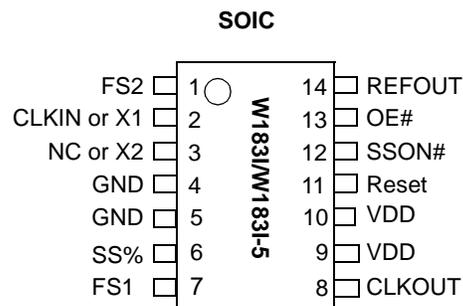| SS%	W183I Output	W183I-5 Output
0	$F_{in} \geq F_{out} \geq F_{in} - 1.25\%$	$F_{in} + 0.625\% \geq F_{in} \geq - 0.625\%$
1	$F_{in} \geq F_{out} \geq F_{in} - 3.75\%$	$F_{in} + 1.875\% \geq F_{in} \geq -1.875\%$

Table 2. Frequency Range Selection

FS2	FS1	Frequency Range
0	0	28 MHz ≤ F_{IN} ≤ 36 MHz
0	1	36 MHz ≤ F_{IN} ≤ 48 MHz
1	0	46 MHz ≤ F_{IN} ≤ 57 MHz
1	1	57 MHz ≤ F_{IN} ≤ 75 MHz

Simplified Block Diagram
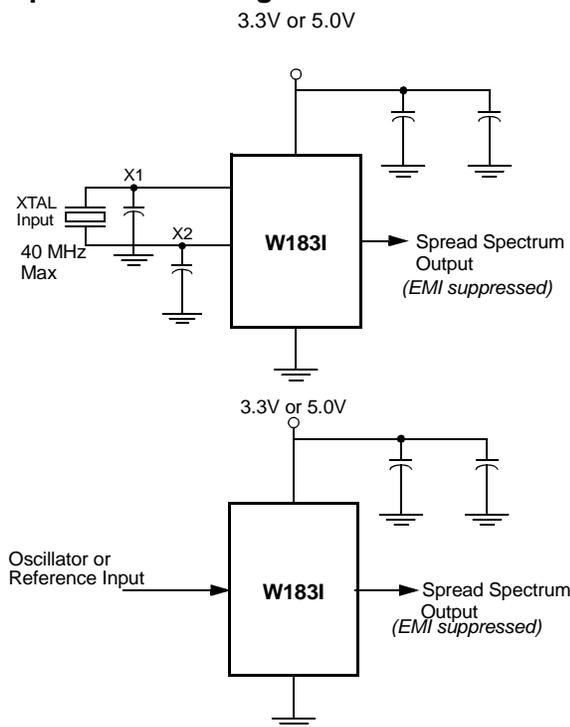
Pin Configuration

PREMIS is a trademark of Cypress Semiconductor Corporation.

Pin Definitions

Pin Name	Pin No.	Pin Type	Pin Description
CLKOUT	8	O	***Output Modulated Frequency***: Frequency modulated copy of the input clock (SSON# asserted).
REFOUT	14	O	***Non-Modulated Output:*** This pin provides a copy of the reference frequency. This output will not have the Spread Spectrum feature regardless of the state of logic input SSON#.
CLKIN or X1	2	I	***Crystal Connection or External Reference Frequency Input:*** This pin has dual functions. It may either be connected to an external crystal, or to an external reference clock.
NC or X2	3	I	***Crystal Connection:*** Input connection for an external crystal. If using an external reference, this pin must be left unconnected.
SSON#	12	I	***Spread Spectrum Control (Active LOW):*** Asserting this signal (active LOW) turns the internal modulation waveform on. This pin has an internal pull-down resistor.
SS%	6	I	***Modulation Width Selection:*** When Spread Spectrum feature is turned on, this pin is used to select the amount of variation and peak EMI reduction that is desired on the output signal. This pin has an internal pull-up resistor.
OE#	13	I	***Output Enable (Active LOW):*** When this pin is held HIGH, the output buffers are placed in a high-impedance mode. This pin has an internal pull-down resistor.
Reset	11	I	***Modulation Profile Restart:*** A rising edge on this input restarts the modulation pattern at the beginning of its defined path. This pin has an internal pull-down resistor.
FS1:2	7, 1	I	***Frequency Selection Bits:*** These pins select the frequency range of operation. Refer to *Table 2*. These pins have internal pull-up resistors.
VDD	9, 10	P	***Power Connection:*** Connected to 3.3V or 5V power supply.
GND	4, 5	G	***Ground Connection:*** Connect all ground pins to the common ground plane.

Overview

The W183I product is one of a series of devices in the Cypress PREMIS family. The PREMIS family incorporates the latest advances in PLL spread spectrum frequency synthesizer techniques. By frequency modulating the output with a low frequency carrier, peak EMI is greatly reduced. Use of this technology allows systems to pass increasingly difficult EMI testing without resorting to costly shielding or redesign.

In a system, not only is EMI reduced in the various clock lines, but also in all signals which are synchronized to the clock. Therefore, the benefits of using this technology increase with the number of address and data lines in the system. The Simplified Block Diagram shows a simple implementation.

Functional Description

The W183I uses a phase-locked loop (PLL) to frequency modulate an input clock. The result is an output clock whose frequency is slowly swept over a narrow band near the input signal. The basic circuit topology is shown in *Figure 1*. The input reference signal is divided by Q and fed to the phase detector. A signal from the VCO is divided by P and fed back to the phase detector also. The PLL will force the frequency of the VCO output signal to change until the divided output signal and the divided reference signal match at the phase detector input. The output frequency is then equal to the ratio of P/Q

times the reference frequency. (Note: For the W183I the output frequency is equal to the input frequency.) The unique feature of the Spread Spectrum Frequency Timing Generator is that a modulating waveform is superimposed at the input to the VCO. This causes the VCO output to be slowly swept across a predetermined frequency band.

Because the modulating frequency is typically 1000 times slower than the fundamental clock, the spread spectrum process has little impact on system performance.

Frequency Selection With SSFTG

In Spread Spectrum Frequency Timing Generation, EMI reduction depends on the shape, modulation percentage, and frequency of the modulating waveform. While the shape and frequency of the modulating waveform are fixed for a given frequency, the modulation percentage may be varied.

Using frequency select bits (FS2:1 pins), the frequency range can be set (see *Table 2*). Spreading percentage is set with pin SS% as shown in *Table 1*.

A larger spreading percentage improves EMI reduction. However, large spread percentages may either exceed system maximum frequency ratings or lower the average frequency to a point where performance is affected. For these reasons, spreading percentages between 0.5% and 2.5% are most common.
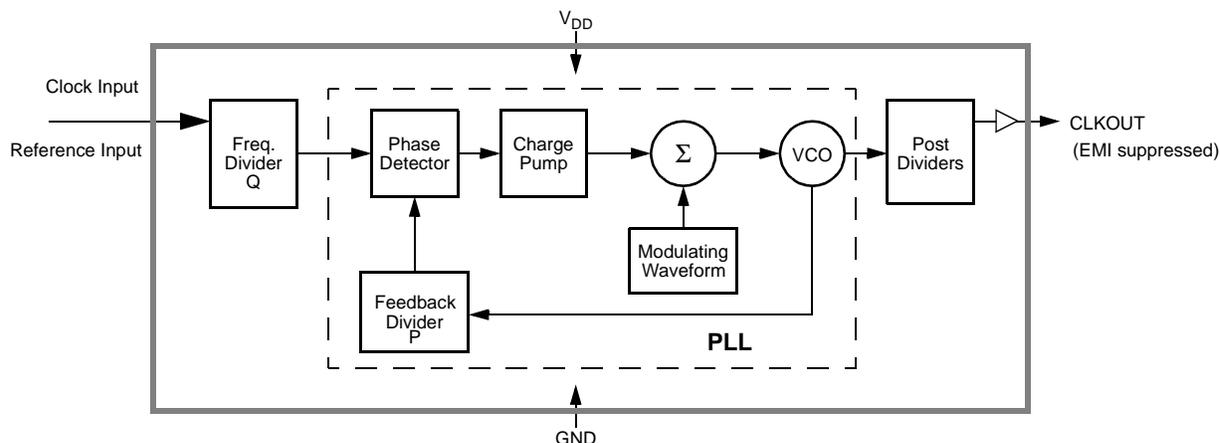
Figure 1. Functional Block Diagram

Spread Spectrum Frequency Timing Generation

The device generates a clock that is frequency modulated in order to increase the bandwidth that it occupies. By increasing the bandwidth of the fundamental and its harmonics, the amplitudes of the radiated electromagnetic emissions are reduced. This effect is depicted in *Figure 2*.

As shown in *Figure 2*, a harmonic of a modulated clock has a much lower amplitude than that of an unmodulated signal. The reduction in amplitude is dependent on the harmonic number and the frequency deviation or spread. The equation for the reduction is:

$$dB = 6.5 + 9*log_{10}(P) + 9*log_{10}(F)$$

Where *P* is the percentage of deviation and *F* is the frequency in MHz where the reduction is measured.

The output clock is modulated with a waveform depicted in *Figure 3*. This waveform, as discussed in "Spread Spectrum Clock Generation for the Reduction of Radiated Emissions" by Bush, Fessler, and Hardin produces the maximum reduction in the amplitude of radiated electromagnetic emissions. *Figure 3* details the Cypress spreading pattern. Cypress does offer options with more spread and greater EMI reduction. Contact your local Sales representative for details on these devices.
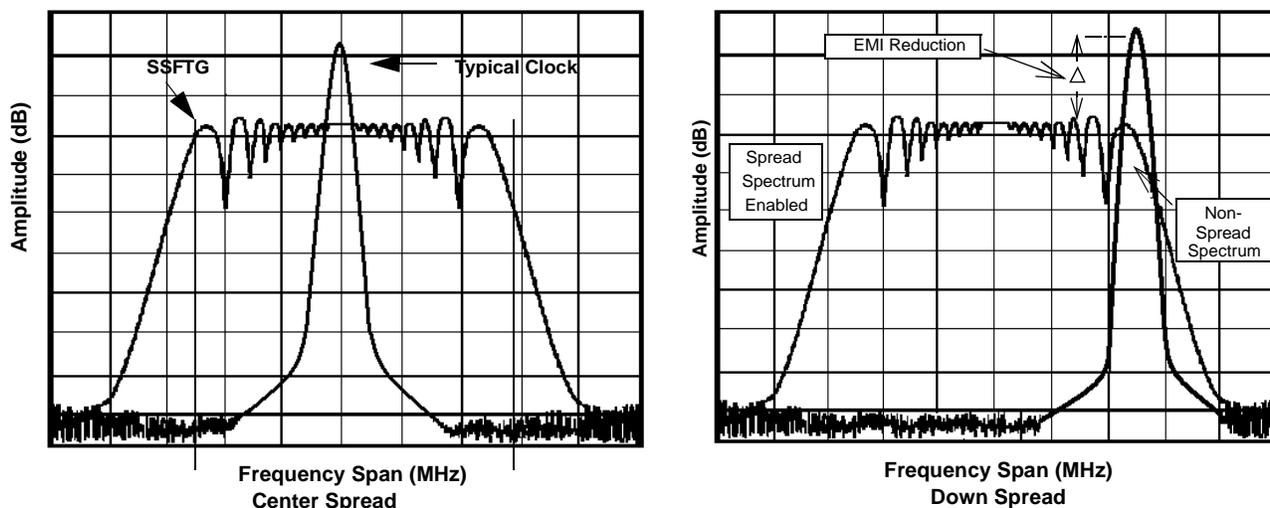

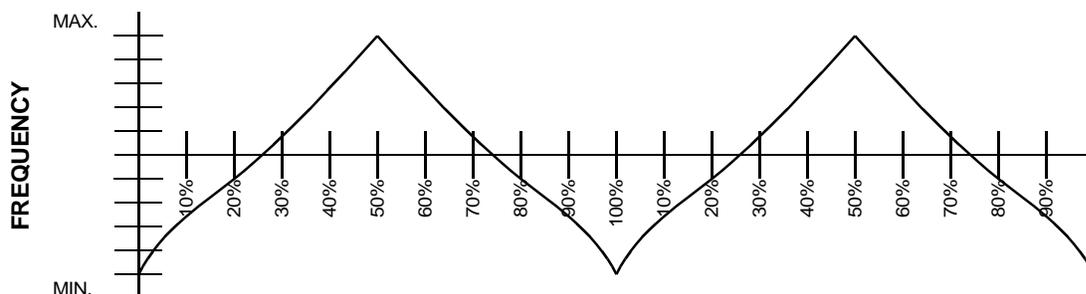Figure 2. Clock Harmonic with and without SSCG Modulation Frequency Domain Representation

Figure 3. Typical Modulation Profile

Absolute Maximum Ratings[1]

Stresses greater than those listed in this table may cause permanent damage to the device. These represent a stress rating only. Operation of the device at these or any other conditions above those specified in the operating sections of this specification is not implied. Maximum conditions for extended periods may affect reliability.

Parameter	Description	Rating	Unit
V_{DD}, V_{IN}	Voltage on any pin with respect to GND	−0.5 to +7.0	V
T_{STG}	Storage Temperature	−65 to +150	°C
T_A	Operating Temperature	−40 to +85	°C
T_B	Ambient Temperature under Bias	−55 to +125	°C
P_D	Power Dissipation	0.5	W

Note:
1. Single Power Supply: The voltage on any input or I/O pin cannot exceed the power pin during power-up.

DC Electrical Characteristics: −40°C < T_A < +85°C, V_{DD} = 3.3V ±5%

Parameter	Description	Test Condition	Min.	Typ.	Max.	Unit
I_{DD}	Supply Current			18	32	mA
t_{ON}	Power Up Time	First locked clock cycle after Power Good			5	ms
V_{IL}	Input Low Voltage				0.8	V
V_{IH}	Input High Voltage		2.4			V
V_{OL}	Output Low Voltage				0.4	V
V_{OH}	Output High Voltage		2.4			V
I_{IL}	Input Low Current	Note 2	−50			μA
I_{IH}	Input High Current	Note 2			50	μA
I_{OL}	Output Low Current	@ 0.4V, V_{DD} = 3.3V		15		mA
I_{OH}	Output High Current	@ 2.4V, V_{DD} = 3.3V		15		mA
C_I	Input Capacitance				7	pF
R_P	Input Pull-Up Resistor			500		kΩ
Z_{OUT}	Clock Output Impedance			25		Ω

Note:
2. Inputs FS1:2 have a pull-up resistor, Input SSON# has a pull-down resistor.

DC Electrical Characteristics: $-40°C < T_A < +85°C$, $V_{DD} = 5V \pm 10\%$

Parameter	Description	Test Condition	Min.	Typ.	Max.	Unit
I_{DD}	Supply Current			30	50	mA
t_{ON}	Power Up Time	First locked clock cycle after Power Good			5	ms
V_{IL}	Input Low Voltage				$0.15V_{DD}$	V
V_{IH}	Input High Voltage		$0.7V_{DD}$			V
V_{OL}	Output Low Voltage				0.4	V
V_{OH}	Output High Voltage		2.4			V
I_{IL}	Input Low Current	Note 3	–50			µA
I_{IH}	Input High Current	Note 3			50	µA
I_{OL}	Output Low Current	@ 0.4V, V_{DD} = 5V		24		mA
I_{OH}	Output High Current	@ 2.4V, V_{DD} = 5V		24		mA
C_I	Input Capacitance				7	pF
R_P	Input Pull-Up Resistor			500		kΩ
Z_{OUT}	Clock Output Impedance			25		Ω

AC Electrical Characteristics: $T_A = -40°C < T_A < +85°C$, $V_{DD} = 3.3V \pm 5\%$ or $5V \pm 10\%$

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
f_{IN}	Input Frequency	Input Clock	28		75	MHz
f_{OUT}	Output Frequency	Spread Off	28		75	MHz
f_{XOSC}	Crystal Oscillator Frequency		28		40	MHz
t_R	Output Rise Time	15-pF load, 0.8V–2.4V		2	5	ns
t_F	Output Fall Time	15-pF load, 2.4V–0.8V		2	5	ns
t_{OD}	Output Duty Cycle	15-pF load	40		60	%
t_{ID}	Input Duty Cycle		40		60	%
t_{JCYC}	Jitter, Cycle-to-Cycle			250	300	ps
	Harmonic Reduction	f_{out} = 40 MHz, third harmonic measured, reference board, 15-pF load	8			dB

Note:
3. Inputs FS2:1 have a pull-up resistor, Input SSON# has a pull-down resistor.

## Application Information

Recommended Circuit Configuration

For optimum performance in system applications the power supply decoupling scheme shown in *Figure 4* should be used.

VDD decoupling is important to both reduce phase jitter and EMI radiation. The 0.1-µF decoupling capacitor should be placed as close to the V_{DD} pin as possible, otherwise the in-creased trace inductance will negate its decoupling capability. The 10-µF decoupling capacitor shown should be a tantalum type. For further EMI protection, the V_{DD} connection can be made via a ferrite bead, as shown.
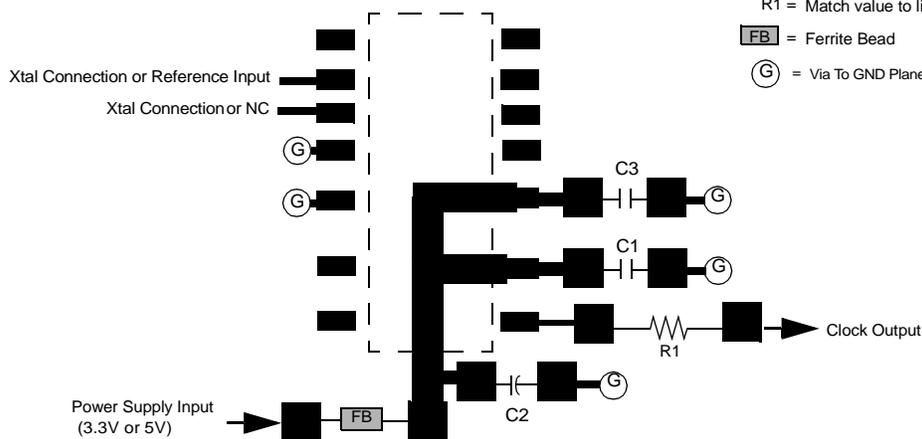
Recommended Board Layout

Figure 5 shows a recommended a 2-layer board layout
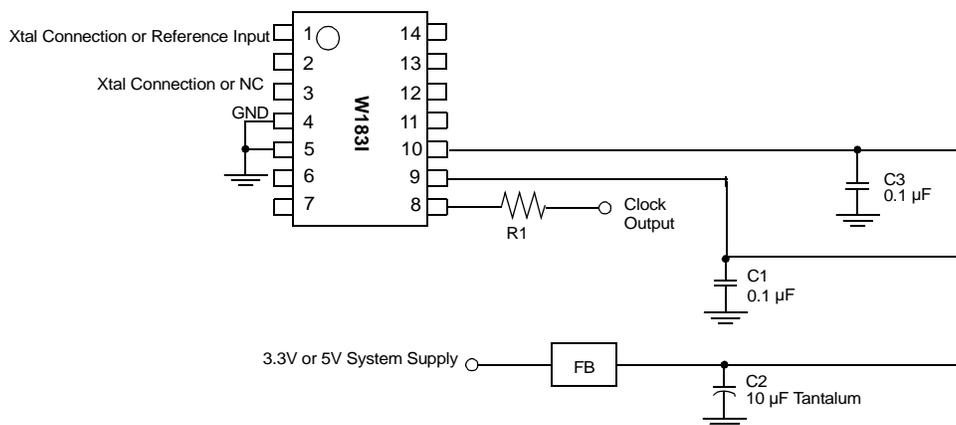
**Figure 4. Recommended Circuit Configuration**

C1, C3 = High frequency supply decoupling capacitor (0.1-µF recommended).

C2 = Common supply low frequency decoupling capacitor (10-µF tantalum recommended).

R1 = Match value to line impedance

FB = Ferrite Bead

Ⓖ = Via To GND Plane

Figure 5. Recommended Board Layout (2-Layer Board)

Ordering Information

Ordering Code	Package Name	Package Type	Temperature Range
W183I W183I-5	G	14-Pin Plastic SOIC (150-mil)	I = Industrial (–40°C to 85°C)

Package Diagram

14-Pin Small Outline Integrated Circuit (SOIC, 150-mil)
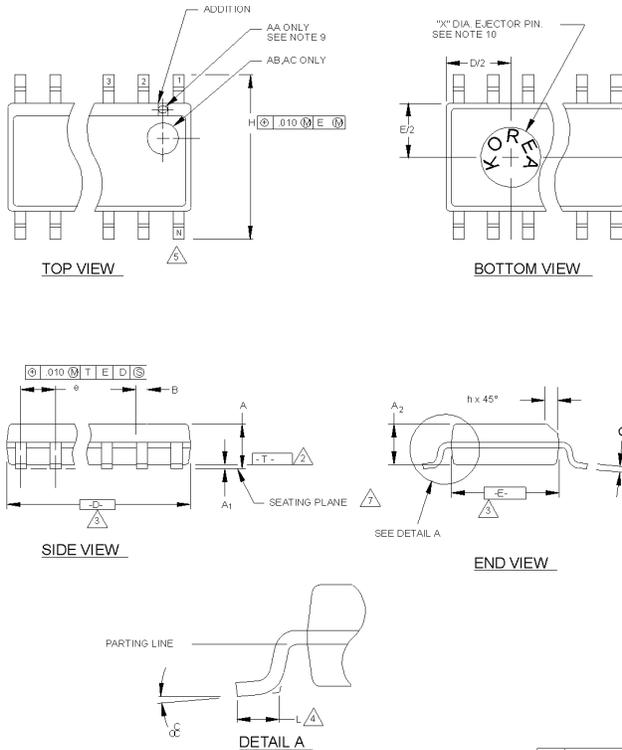
NOTES:

1. MAXIMUM DIE THICKNESS ALLOWABLE IS .015.
2. DIMENSIONING & TOLERANCES PER ANSI.Y14.5M - 1982.
3. "T" IS A REFERENCE DATUM.
4. "D" & "E" ARE REFERENCE DATUMS AND DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS, BUT DOES INCLUDE MOLD MISMATCH AND ARE MEASURED AT THE MOLD PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
5. "L" IS THE LENGTH OF TERMINAL FOR SOLDERING TO A SUBSTRATE.
6. "N" IS THE NUMBER OF TERMINAL POSITIONS.
7. TERMINAL POSITIONS ARE SHOWN FOR REFERENCE ONLY.
8. FORMED LEADS SHALL BE PLANAR WITH RESPECT TO ONE ANOTHER WITHIN .003 INCHES AT SEATING PLANE.
9. THE APPEARANCE OF PIN #1 I.D ON THE 8 LD IS OPTIONAL, ROUND TYPE ON SINGLE LEADFRAME AND RECTANGULAR TYPE ON MATRIX LEADFRAME.
10. COUNTRY OF ORIGIN LOCATION AND EJECTOR PIN ON PACKAGE BOTTOM IS OPTIONAL AND DEPEND ON ASSEMBLY LOCATION.
11. CONTROLLING DIMENSION: INCHES.

THIS TABLE IN INCHES

SYMBOL	COMMON DIMENSIONS			NOTE	NOTE VARI-ATIONS	3 D			5 N
	MIN.	NOM.	MAX.			MIN.	NOM.	MAX.	
A	.061	.064	.068		AA	.189	.194	.196	8
A1	.004	.006	.0098		AB	.337	.342	.344	14
A2	.055	.058	.061		AC	.386	.391	.393	16
B	.0138	.016	.0192						
C	.0075	.008	.0098						
D	SEE VARIATIONS			3					
E	.150	.155	.157						
e	.050 BSC								
H	.230	.236	.244						
h	.010	.013	.016						
L	.016	.025	.035						
N	SEE VARIATIONS			5					
α	0°	5°	8°						
X	.085	.093	.100						

THIS TABLE IN MILLIMETERS

SYMBOL	COMMON DIMENSIONS			NOTE	NOTE VARI-ATIONS	3 D			5 N
	MIN.	NOM.	MAX.			MIN.	NOM.	MAX.	
A	1.55	1.63	1.73		AA	4.80	4.93	4.98	8
A1	0.127	0.15	0.25		AB	8.58	8.69	8.74	14
A2	1.40	1.47	1.55		AC	9.80	9.93	9.98	16
B	0.35	0.41	0.49						
C	0.19	0.20	0.25						
D	SEE VARIATIONS			3					
E	3.81	3.94	3.99						
e	1.27 BSC								
H	5.84	5.99	6.20						
h	0.25	0.33	0.41						
L	0.41	0.64	0.89						
N	SEE VARIATIONS			5					
α	0°	5°	8°						
X	2.16	2.36	2.54						

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REV.	ECN NO.	Issue Date	Orig. of Change	Description of Change
**	108763	09/14/01	IKA	New spec.
*A	122684	12/27/02	RBI	Add power up requirements to maximum ratings information.